### ....

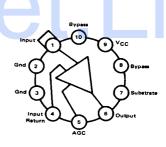
# Device Temperature Range Package MC1550F -55°C to +125°C Ceramic Flat MC1550G -55°C to +125°C Metal Can

## MC1550G

RF — IF AMPLIFIER SILICON MONOLITHIC INTEGRATED CIRCUIT



G SUFFIX ETAL PACKAGE CASE 603B



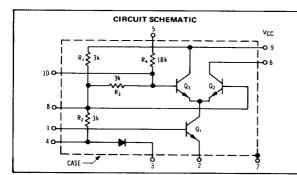
#### RF - IF AMPLIFIER

... a versatile, common-emitter, common-base cascode circuit for use in communications applications. See Application Note AN-215A for additional information.

- Constant Input Impedance over entire AGC range
- Extremely Low y 12 4.3 μmhos at 60 MHz
- High Power Gain 30 dB @ 60 MHz (0.5 MHz BW)
- Good Noise Figure 5 dB @ 60 MHz

#### MAXIMUM RATINGS (TA = +25°C unless otherwise noted)

Rating	Symbol	Value	Unit	
Power Supply Voltage, Pin 9	Vcc	20	Vdc	
AGC Supply Voltage	VAGC	20	Vdc	
Input Differential Voltage, Pin 1 to Pin 4 (RS = 500 ohms)	VID	±5.0	V(rms)	
Power Dissipation (Package Limitation) Metal Can Derate above T <sub>A</sub> = +25°C Flat Package Derate above T <sub>A</sub> = +25°C	PD	680 4.6 500 3.3	mW mW/ <sup>o</sup> C mW mW/ <sup>o</sup> C	
Operating Ambient Temperature Range	TA	-55 to +125	°C	
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°c	



#### CIRCUIT DESCRIPTION

The MC1550 is built with monolithic fabrication techniques utilizing diffused resistors and small-geometry transistors. Excellent AGC performance is obtained by shunting the signal through the AGC transistor Q, maintaining the operating point of the input transistor Q. This keeps the input impedance constant over the entire AGC range.

The amplifier is intended to be used in a common-emitter,

ommon-base configuration (Q<sub>1</sub> and Q<sub>2</sub>) with Q<sub>1</sub> acting as an AGC transistor. The input signal is applied between pins 1 and 4, where pin 4 is ac-coupled to ground. DC source resistance between pins 1 and 4 should be small (less than 100 ohms). Pins 2 and 3 should be connected together and grounded. Pins 8 and 10 should be bypassed to ground. The positive supply voltage is applied at pin 9 and at higher frequencies, pin 9 should also be bypassed to ground. The output is taken between pins 6 and 9. The substrate is connected to pin 7 and should be grounded. AGC voltage is applied to pin 5.

#### ELECTRICAL CHARACTERISTICS (V+ = +6 Vdc, TA = +25°C)

Characteristic	Conditions	Figure	Symbol	Min	Тур	Max	Unit
DC CHARACTERISTICS							
Output Voltage	V <sub>AGC</sub> = 0 Vdc V <sub>AGC</sub> = +6 Vdc	1	٧o	3.80 5.90	_	4.65 6.00	Vdc
Test Voltage	V <sub>AGC</sub> = 0 Vdc V <sub>AGC</sub> = +6 Vdc	1	V8	2.85 3.25	-	3.40 3.80	Vdc
Supply Drain Current	V <sub>AGC</sub> = 0 Vdc V <sub>AGC</sub> = +6 Vdc	1	aا	_	_	2.2 2.5	mAdc
AGC Supply Drain Current	VAGC = 0 Vdc VAGC = +6 Vdc	1	IAGC	_	-	-0.2 0.18	mAdc

#### **SMALL-SIGNAL CHARACTERISTICS**

Small-Signal Voltage Gain	f = 500 kHz	2	Av	22		29	dB
Bandwidth	-3.0 dB	2	BW	22	_	_	MHz
Transducer Power Gain	f = 60 MHz, BW = 6 MHz	3	Ар	-	25	_	dB
	f = 100 MHz, BW = 6 MHz	L	j	-	21	-	

#### TYPICAL CHARACTERISTICS

(V<sub>CC</sub> = 6.0 Vdc, T<sub>A</sub> = +25°C unless otherwise noted.)

FIGURE 1 - DC CHARACTERISTICS TEST CIRCUIT

FIGURE 2 - VOLTAGE GAIN AND BANDWIDTH TEST CIRCUIT

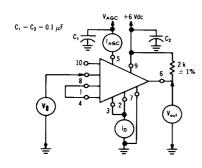
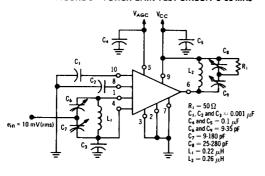


FIGURE 3 - POWER GAIN TEST CIRCUIT @ 60 MHz



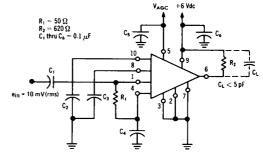
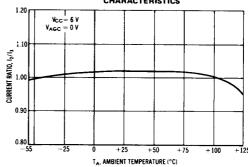


FIGURE 4 – DRAIN CURRENT TEMPERATURE CHARACTERISTICS





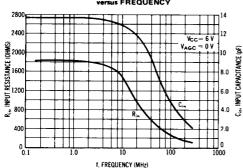
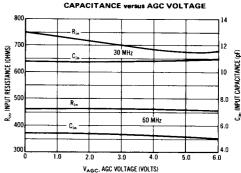
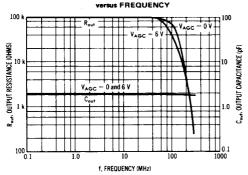


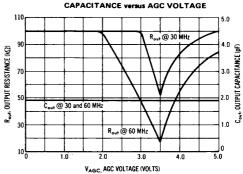
FIGURE 6 - INPUT RESISTANCE AND



#### FIGURE 7 - OUTPUT RESISTANCE AND CAPACITANCE



#### FIGURE 8 - OUTPUT RESISTANCE AND



#### FIGURE 9 - MAXIMUM TRANSDUCER POWER GAIN versus FREQUENCY

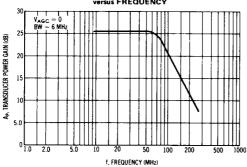
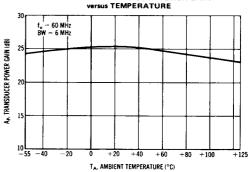
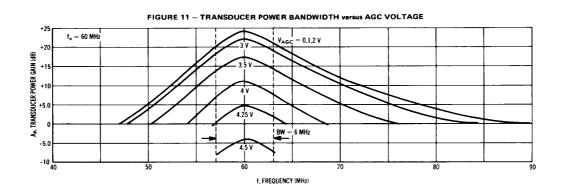
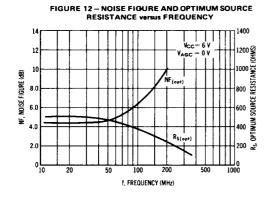


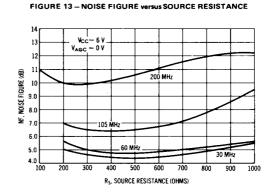
FIGURE 10 - TRANSDUCER POWER GAIN

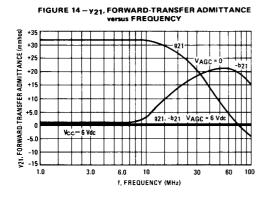


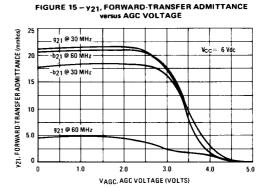
#### TYPICAL CHARACTERISTICS (continued)











6-33

#### FIGURE 16 - y12, REVERSE TRANSFER-ADMITTANCE versus FREQUENCY

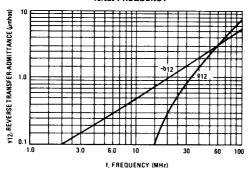
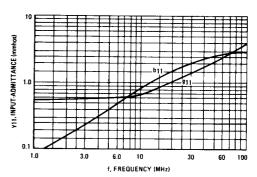


FIGURE 17 - y11, INPUT-ADMITTANCE versus FREQUENCY



The y12 shown in Figure 16 illustrates the extremely low feedback of the MC1550 with no contribution from the external mounting circuitry. However, in many cases the external circuitry may contribute as much or more to the total feedback

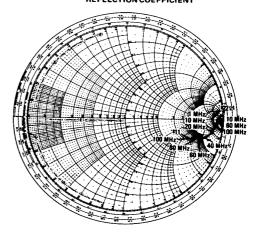
To perform more accurate design calculations of gain, stability, and input - output impedances it is recommended that the designer first determine the total feed back of device plus circuitry.

This can be done in one of two ways:

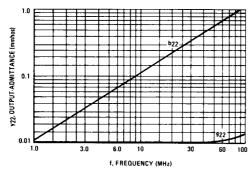
than does the MC1550.

- (1) Measure the total y12 or s12 of the MC1550 installed in its mounting circuitry, or
- Measure the y<sub>12</sub> of the circuitry alone (without the MC1550 installed) and add the circuit y<sub>12</sub> to the y<sub>12</sub> for the MC1550 given in Figure 16.

FIGURE 19 - s<sub>11</sub> AND s<sub>22</sub>, INPUT AND OUTPUT REFLECTION COEFFICIENT



#### FIGURE 18 - y22, OUTPUT-ADMITTANCE versus FREQUENCY



# TYPICAL CHARACTERISTICS (continued) ( $V_{CC} = 6.0 \ V_{dc}, T_A = +25^{o}_{C} \ unless otherwise noted.)$

